

FIG. 1. Optical image and sketch of 10×10 square array.

The junction area is $9 \mu\text{m}^2$ and their critical current density is about $1.1 \text{ KA}/\text{cm}^2$ for square array, and $0.1 \text{ KA}/\text{cm}^2$ for triangular array, with a typical spread of junction parameters of about 5%. The square arrays consist of 10 columns by 10 rows and have the cell area $S = 38 \mu\text{m}^2$. The triangular arrays are made of 12 columns by 12 rows and have $S = 160 \mu\text{m}^2$. All arrays

FIG. 3. (a) Enlargement of digitally stored I - V curves in the region between zero and $4V_g$; (b-e) LTSLM images of resistive states of the array at the bias points close to the $4V_g$.

By using the LTSLM, we have systematically imaged different resistive configurations biased at various fine resistive branches of the I - V curves. The experimental procedure is the following: the number n of switched rows is fixed by biasing the array at voltages $V \simeq nV_g$. Then LTSLM images of the sample are recorded at a constant bias value. Typical images from the square array are shown in Fig. 3(b)-(e). The black spots correspond to the junctions that are in the resistive state. The junctions that are in the superconducting state do not appear on the array image. As expected, the images show that the number of rows which are in the resistive state is equal to the number n of gap voltages selected by the bias point. To trap a different resistive configuration, we always increased the bias current I above I_c^{array} , the array critical current, and then reduced it to the low level.

Similarly to the experimental results of Ref. [7], we

FIG. 4. LTSLM images of more complicated dynamic states observed at the bias points close to $7V_g$ voltage region.

In the following, we present numerical simulations of the dynamics of underdamped arrays. Calculations were performed using the resistively shunted model for Josephson junctions and the usual analysis for superconductive loops with only self-inductances taken into account, *i.e.* the Nakajima-Sawada equations [13]. For a discussion of these equations and the application limits see Refs. [6,8]. The phase configuration of a row switched state was used as initial condition for the next run.

We simulated large (10×10) and small (2×10) square arrays with various parameter β_L between 0.5 and 2. In all cases, the simulations well reproduce the branching of I - V curves and meandering character of the finite voltage paths. Moreover, in order to check the influence of self-inductance effects the simulation were carried out for the arrays with a small parameter $\beta_L = 0.1$. A simulated I - V curve with three different branches and the corresponding voltage distributions for the 2×10 array are

shown in Fig. 5. Resistive states with both single and double meanders have been trapped (Fig. 5). The appearance of the meandering is qualitatively similar to the experimental images shown in Fig. 3(b-e). The simulations have been carried out in the presence of finite magnetic field in order to prevent the simultaneous switching of all the array rows [8]. It leads to the decrease of the critical current and the appearance of the flux-flow region where I - V curves are highly non linear (Fig. 5).

We have found that, in the absence of disorder, the probability of the appearance of a meander in two row array is about 1.8% per horizontal junction. Surprisingly, in the presence of specially introduced disorder up to 20% the numerical simulations show no increase of the rate of appearance and no preferred position of the meanders. Due to this fact, we conclude that the broken symmetry row switching appears due to an intrinsic instability

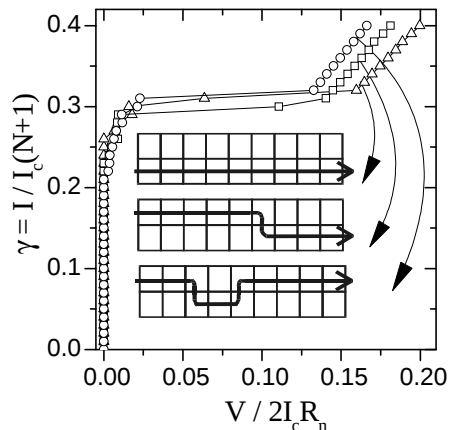


FIG. 5. Numerically simulated I - V characteristics of a two row array and the corresponding voltage paths at $\gamma = 0.4$. I_c is the single junction critical current.

of the superconducting state, *i.e.* a change of the initial conditions can lead to the appearance of a different percolative voltage path. The numerical analysis of the two row array also allows to find out some peculiarities of the new dynamic states. When the junctions switched to the resistive state form a straight line in the top or bottom row (no meandering), the array has the highest resistance, $R_n/(N+1)$ (triangle symbols in Fig. 5), where N is the total number of cells in the row and R_n is the normal resistance of one junction. In the case when the voltage path with one meandering occurs, the array shows a lower resistance, $R_n/(N+2)$ (square, Fig. 5). Now there is one more junction connected in parallel to the resistive path, with respect to the case of no meandering. For the same reason, the meanders across two horizontal junctions corresponds, to the resistance $R_n/(N+3)$ (circle, Fig. 5). The presence of meanders shifts the array I - V curve to the left and this resistance scaling explains the

experimentally observed fine branching of the I - V curves.

We have found that the above dynamic states are stable in a wide range of voltages, *i.e.* we have not observed direct switching between branches. This is due to the too large energy necessary for the junction capacitance recharge in underdamped arrays [12]. So, only switching from the superconducting state allows to trap these dynamic states.

Our analysis using the Kirchhoff's current laws shows that, in the case of meandering, the dc superconducting current flows via the horizontal junctions. Moreover, this current increases from the row boundary to the cell where the meandering occurs. This current configuration is different from that without meanders. In the latter case the horizontal junctions are not active and dc superconducting current flows only via the vertical junctions.

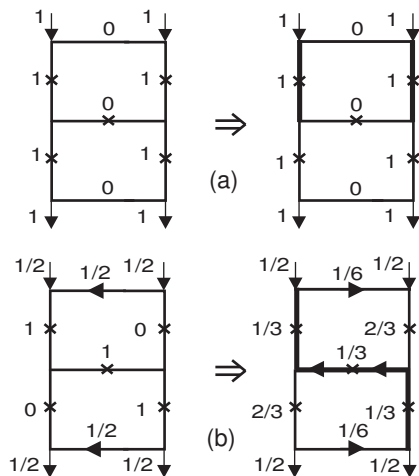


FIG. 6. Sketches of metastable superconducting and resistive states for a small array with two plaquettes containing three junctions per cell: (a) mesh currents are equal to zero, (b) mesh currents are different from zero. Thick solid lines show the parts of the array switched to resistive states, and numbers are the local dc currents normalized to I_c .

All these features can be explained, at least qualitatively, by the presence of metastable superconducting states in 2D Josephson arrays. We analyze these states for a simple case of two plaquettes with 5 junctions (Fig. 6). In the absence of magnetic field, the most stable superconducting state is the one with all mesh currents equal zero. At the bias current $I = 2I_c$ the vertical junctions switch from superconducting state to resistive state with straight resistive rows (dc mesh currents are still zero) (Fig. 6(a)). However, this system has another peculiar state with finite values of mesh currents, as shown in Fig. 6(b). At $I = I_c$ this system can support a superconducting state with the Josephson phases of the horizontal junction and one vertical junction per row being equal to $\pi/2$. The Josephson phases of the remaining vertical junctions are equal to π . This metastable state supports finite mesh currents $I_c/2$ and switches to the dy-

namic (resistive) state with a meander via the horizontal junction. The mesh currents decrease to the value of $I_c/6$ and change sign during the switching process, which results in a stable dynamic state with meandering. Thus, the dynamic states with meandered dc voltage drop are "fingerprints" of metastable superconducting states with non zero mesh currents and active horizontal junctions. The state appears only when there are at least three junctions per cell and it exists also in the limit of zero linear self-inductance and zero magnetic field [14]. That is different from the case of single- and double-junction SQUIDs, where metastable superconducting states appear only in the limit of large self-inductance [12]. Since the above discussed metastable state exists in the limit of zero inductance, the small arrays with few plaquettes can be suitable system to observe the effect of macroscopic quantum coherence at low temperatures [12,15].

It appears that also large 2D arrays can provide various metastable superconducting states that lead to the broken symmetry in row switching process. Theoretical and experimental investigation of these metastable superconducting states and their dependence on the externally applied magnetic field are in progress.

This work was partially supported by the European Office of Aerospace Research and Development (EOARD), the Alexander von Humboldt Stiftung, the German-Israeli Foundation, and the German-Italian DAAD/Vigoni exchange program.

* Unit  INFM Salerno and Science Faculty, University of Sannio Via Port'Arsa 11, 82100 Benevento, Italy

† OXXEL GmbH, Technologiepark Universit t, Fahrenheitstrasse 9, D-28359 Bremen, Germany

- [1] S.H. Strogatz, *Nonlinear Dynamics and Chaos: With Applications to Physics, Biology, Chemistry, and Engineering*, Addison-Wesley, Reading, MA (1994).
- [2] H.S.J. van der Zant, C.J. M ller, L.J. Geerlings, C.J.P.M. Harmans, and J.E. Mooij, Phys. Rev. **B38**, 5154 (1988).
- [3] W. Yu, K.H. Lee, and D. Stroud, Phys. Rev. **B47**, 5906 (1993).
- [4] N. Thyssen, A. V. Ustinov, and H. Kohlstedt, J. Low.Temp. Phys. **106**, 201 (1997).
- [5] R. Kleiner and P. M ller, Phys. Rev. **B49**, 1327 (1994).
- [6] G. Filatrella and K. Wiesenfeld, J. Appl. Phys. **78**, 1878 (1995).
- [7] S.G. Lachenmann, T. Doderer, D. Hoffmann, R.P. H bener, P.A.A. Booi, and S.P. Benz, Phys. Rev. **B50**, 3158 (1994).
- [8] M. Barahona and S. Watanabe, Phys. Rev. **B57**, 10893 (1998).
- [9] J. R. Phillips, H.S.J. van der Zant, and T. P. Orlando, Phys. Rev. **B50**, 9380 (1994).
- [10] A. G. Sivakov, A. P. Zhuravel', O. G. Turutanov, and I.

- M. Dmitrenko, Appl. Surf. Sci, **106**, 390, (1996).
- [11] HYPRES Inc., Elmsford, NY 10523.
 - [12] K. K. Likharev, *Dynamics of Josephson junctions and circuits*, Gordon and Breach, New York, 1981.
 - [13] K. Nakajima and Y. Sawada, J. Appl. Phys. **52**, 5732 (1981).
 - [14] A similar state can be found in a single anisotropic plaquette with three junctions per cell when the parameter of anisotropy $\eta = I_{ch}/I_{cv} > 1/(2\sqrt{2})$ (M. V. Fistul, to be published). Here, I_{ch} and I_{cv} are, respectively, the critical currents of the horizontal and vertical junctions.
 - [15] J. E. Mooij, T. P. Orlando, L. Levitov, L. Tian, C. H. van der Wal, and S. Lloyd, Science **285**, 1036 (1999).